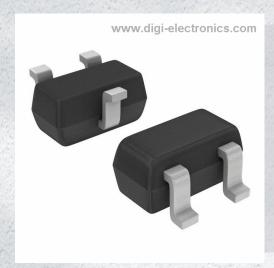


# **DTA114EET1G Datasheet**



https://www.DiGi-Electronics.com

DiGi Electronics Part Number DTA114EET1G-DG

Manufacturer onsemi

Manufacturer Product Number DTA114EET1G

Description TRANS PREBIAS PNP 50V 0.1A SC75

Detailed Description Pre-Biased Bipolar Transistor (BJT) PNP - Pre-Biase

d 50 V 100 mA 200 mW Surface Mount SC-75, SOT-4

16



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.



# **Purchase and inquiry**

Manufacturer Product Number:	Manufacturer:
DTA114EET1G	onsemi
Series:	Product Status:
	Active
Transistor Type:	Current - Collector (Ic) (Max):
PNP - Pre-Biased	100 mA
Voltage - Collector Emitter Breakdown (Max):	Resistor - Base (R1):
50 V	10 kOhms
Resistor - Emitter Base (R2):	DC Current Gain (hFE) (Min) @ lc, Vce:
10 kOhms	35 @ 5mA, 10V
Vce Saturation (Max) @ lb, lc:	Current - Collector Cutoff (Max):
250mV @ 300μA, 10mA	500nA
Power - Max:	Mounting Type:
200 mW	Surface Mount
Package / Case:	Supplier Device Package:
SC-75, SOT-416	SC-75, SOT-416
Base Product Number:	
DTA114	

# **Environmental & Export classification**

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8541.21.0095	



# **Digital Transistors (BRT)** R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$

**PNP Transistors with Monolithic Bias Resistor Network** 

# MUN2111, MMUN2111L, MUN5111, DTA114EE, DTA114EM3, NSBA114EF3

This series of digital transistors is designed to replace a single device and its external resistor bias network. The Bias Resistor Transistor (BRT) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a baseemitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space.

#### **Features**

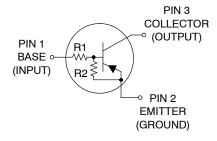
- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

#### **MAXIMUM RATINGS** $(T_A = 25^{\circ}C)$

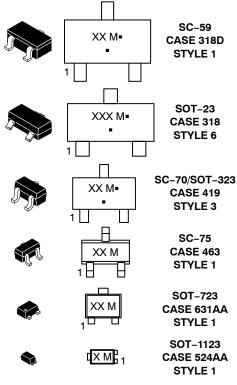
Rating	Symbol	Max	Unit
Collector-Base Voltage	V <sub>CBO</sub>	50	Vdc
Collector-Emitter Voltage	$V_{CEO}$	50	Vdc
Collector Current – Continuous	I <sub>C</sub>	100	mAdc
Input Forward Voltage	$V_{IN(fwd)}$	40	Vdc
Input Reverse Voltage	V <sub>IN(rev)</sub>	10	Vdc

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### **PIN CONNECTIONS**



#### **MARKING DIAGRAMS**



XXX Specific Device Code

= Date Code\* M = Pb-Free Package

(Note: Microdot may be in either location)

\*Date Code orientation may vary depending upon manufacturing location.

#### ORDERING INFORMATION

See detailed ordering, marking, and shipping information in the package dimensions section on page 2 of this data sheet.

NOTE: Some of the devices on this data sheet have been DISCONTINUED. Please refer to the table on page 2.

1

**Table 1. ORDERING INFORMATION** 

Device	Part Marking	Package	Shipping <sup>†</sup>
MUN2111T1G, SMUN2111T1G	6A	SC-59 (Pb-Free)	3000 / Tape & Reel
SMUN2111T3G	6A	SC-59 (Pb-Free)	10000 / Tape & Reel
MMUN2111LT1G, SMMUN2111LT1G	A6A	SOT-23 (Pb-Free)	3000 / Tape & Reel
MMUN2111LT3G, SMMUN2111LT3G	A6A	SOT-23 (Pb-Free)	10000 / Tape & Reel
MUN5111T1G, SMUN5111T1G	6A	SC-70/SOT-323 (Pb-Free)	3000 / Tape & Reel
DTA114EET1G, NSVDTA114EET1G	6A	SC-75 (Pb-Free)	3000 / Tape & Reel
DTA114EM3T5G, NSVDTA114EM3T5G	6A	SOT-723 (Pb-Free)	8000 / Tape & Reel

#### **DISCONTINUED** (Note 1)

NSBA114EF3T5G	F	SOT-1123	8000 / Tape & Reel
		(Pb-Free)	

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

<sup>1.</sup> **DISCONTINUED:** These devices are not recommended for new design. Please contact your **onsemi** representative for information. The most current information on these devices may be available on <a href="https://www.onsemi.com">www.onsemi.com</a>.

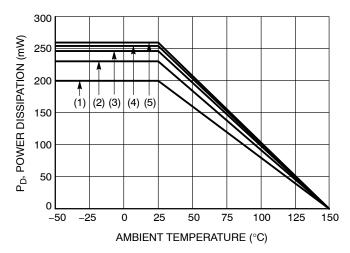


Figure 1. Derating Curve

- (1) SC-75 and SC-70/SOT-323; Minimum Pad
- (2) SC-59; Minimum Pad
- (3) SOT-23; Minimum Pad
- (4) SOT-1123; 100 mm<sup>2</sup>, 1 oz. copper trace
- (5) SOT-723; Minimum Pad

#### Table 2. THERMAL CHARACTERISTICS

	Characteristic	Symbol	Max	Unit
THERMAL CHARACTERISTI	CS (SC-59) (MUN2111)			
Total Device Dissipation $T_A = 25^{\circ}C \qquad (Note 2)$ $(Note 3)$ Derate above 25°C $(Note 3)$	(Note 2)	P <sub>D</sub>	230 338 1.8 2.7	mW mW/°C
Thermal Resistance, Junction to Ambient	(Note 2) (Note 3)	$R_{\thetaJA}$	540 370	°C/W
Thermal Resistance, Junction to Lead (Note 3)	(Note 2)	$R_{ hetaJL}$	264 287	°C/W
Junction and Storage Temper	ature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C
THERMAL CHARACTERISTI	CS (SOT-23) (MMUN2111L)	<u>,                                     </u>	•	
Total Device Dissipation $T_A = 25^{\circ}C \qquad \text{(Note 2)}$ $\text{(Note 3)}$ Derate above 25°C $\text{(Note 3)}$	(Note 2)	P <sub>D</sub>	246 400 2.0 3.2	mW mW/°C
Thermal Resistance, Junction to Ambient	(Note 1) (Note 3)	$R_{ hetaJA}$	508 311	°C/W
Thermal Resistance, Junction to Lead (Note 3)	(Note 2)	$R_{ hetaJL}$	174 208	°C/W
Junction and Storage Temper	ature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C
THERMAL CHARACTERISTI	CS (SC-70/SOT-323) (MUN5111)	<u>,                                     </u>	•	
Total Device Dissipation  T <sub>A</sub> = 25°C (Note 2) (Note 3)  Derate above 25°C (Note 3)	(Note 2)	P <sub>D</sub>	202 310 1.6 2.5	mW mW/°C
Thermal Resistance, Junction to Ambient	(Note 2) (Note 3)	$R_{ hetaJA}$	618 403	°C/W
Thermal Resistance, Junction to Lead (Note 3)	(Note 2)	$R_{ hetaJL}$	280 332	°C/W
Junction and Storage Temper	rature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C
THERMAL CHARACTERISTI	CS (SC-75) (DTA114EE)			
Total Device Dissipation $T_A = 25^{\circ}C \qquad \text{(Note 2)}$ $\text{(Note 3)}$ Derate above 25 $^{\circ}$ C $\text{(Note 3)}$	(Note 2)	P <sub>D</sub>	200 300 1.6 2.4	mW mW/°C
Thermal Resistance, Junction to Ambient	(Note 2) (Note 3)	$R_{ hetaJA}$	600 400	°C/W
Junction and Storage Temper	rature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C
THERMAL CHARACTERISTI	CS (SOT-723) (DTA114EM3)	•	•	
Total Device Dissipation $T_A = 25^{\circ}C \qquad \text{(Note 2)}$ $\text{(Note 3)}$ Derate above 25°C $\text{(Note 3)}$	(Note 2)	P <sub>D</sub>	260 600 2.0 4.8	mW mW/°C
Thermal Resistance, Junction to Ambient	(Note 2) (Note 3)	$R_{\thetaJA}$	480 205	°C/W
Junction and Storage Temper	ature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

- 2. FR-4 @ Minimum Pad.
- 3. FR-4 @ 1.0 x 1.0 Inch Pad.
- 4. FR-4 @ 100 mm², 1 oz. copper traces, still air.
  5. FR-4 @ 500 mm², 1 oz. copper traces, still air.

#### **Table 2. THERMAL CHARACTERISTICS**

Characteristic		Symbol	Max	Unit
THERMAL CHARACTERISTICS (SOT-1123) (NSBA1	14EF3)			
Total Device Dissipation $T_A = 25^{\circ}C \qquad \text{(Note 4)}$ $\text{(Note 5)}$ Derate above 25°C  \text{(Note 4)} $\text{(Note 5)}$		P <sub>D</sub>	254 297 2.0 2.4	mW mW/°C
Thermal Resistance, (Note 4) Junction to Ambient (Note 5)		$R_{ hetaJA}$	493 421	°C/W
Thermal Resistance, Junction to Lead	(Note 4)	$R_{ heta JL}$	193	°C/W
Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

- 2. FR-4 @ Minimum Pad.
- 3. FR-4 @ 1.0 x 1.0 Inch Pad.
- 4. FR-4 @ 100 mm², 1 oz. copper traces, still air.
  5. FR-4 @ 500 mm², 1 oz. copper traces, still air.

#### **Table 3. ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C, unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS			•		
Collector-Base Cutoff Current (V <sub>CB</sub> = 50 V, I <sub>E</sub> = 0)	I <sub>CBO</sub>	-	-	100	nAdc
Collector–Emitter Cutoff Current $(V_{CE} = 50 \text{ V}, I_B = 0)$	I <sub>CEO</sub>	_	-	500	nAdc
Emitter-Base Cutoff Current ( $V_{EB} = 6.0 \text{ V}, I_{C} = 0$ )	I <sub>EBO</sub>	-	-	0.5	mAdc
Collector–Base Breakdown Voltage $(I_C = 10 \mu A, I_E = 0)$	V <sub>(BR)</sub> CBO	50	-	-	Vdc
Collector-Emitter Breakdown Voltage (Note 6) (I <sub>C</sub> = 2.0 mA, I <sub>B</sub> = 0)	V <sub>(BR)</sub> CEO	50	-	-	Vdc
ON CHARACTERISTICS					
DC Current Gain (Note 6) (I <sub>C</sub> = 5.0 mA, V <sub>CE</sub> = 10 V)	h <sub>FE</sub>	35	60	-	
Collector–Emitter Saturation Voltage (Note 6) (I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0.3 mA)	V <sub>CE(sat)</sub>	_	-	0.25	Vdc
Input Voltage (off) $(V_{CE} = 5.0 \text{ V}, I_{C} = 100 \mu\text{A})$	$V_{i(off)}$	_	1.2	0.8	Vdc
Input Voltage (on) (V <sub>CE</sub> = 0.3 V, I <sub>C</sub> = 10 mA)	V <sub>i(on)</sub>	2.5	1.8	-	Vdc
Output Voltage (on) ( $V_{CC} = 5.0 \text{ V}$ , $V_B = 2.5 \text{ V}$ , $R_L = 1.0 \text{ k}\Omega$ )	V <sub>OL</sub>	-	-	0.2	Vdc
Output Voltage (off) ( $V_{CC} = 5.0 \text{ V}, V_B = 0.5 \text{ V}, R_L = 1.0 \text{ k}\Omega$ )	V <sub>OH</sub>	4.9	-	-	Vdc
Input Resistor	R1	7.0	10	13	kΩ
Resistor Ratio	R <sub>1</sub> /R <sub>2</sub>	0.8	1.0	1.2	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

# TYPICAL CHARACTERISTICS MUN2111, MMUN2111L, MUN5111, DTA114EE, DTA114EM3

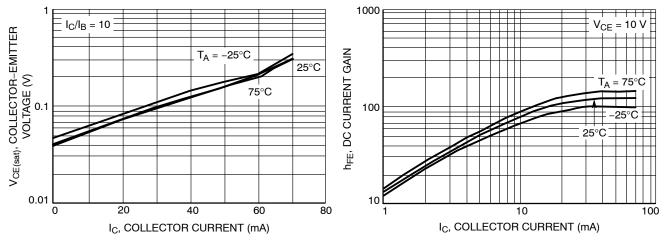


Figure 2. V<sub>CE(sat)</sub> vs. I<sub>C</sub>

Figure 3. DC Current Gain

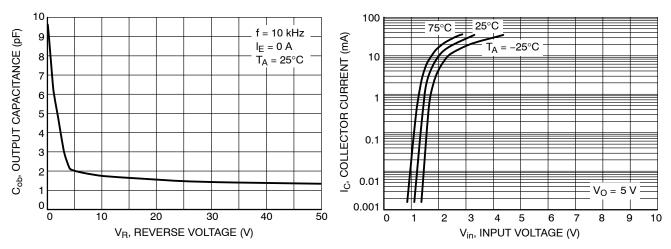


Figure 4. Output Capacitance

Figure 5. Output Current vs. Input Voltage

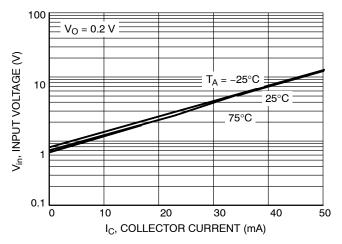
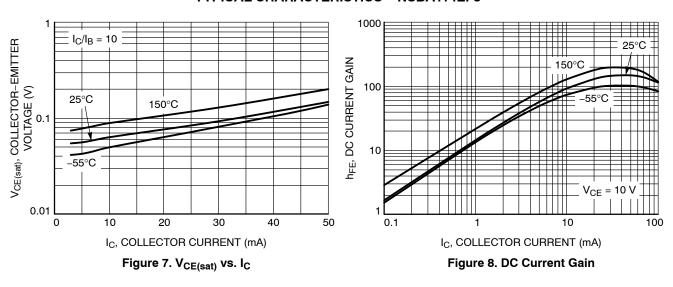


Figure 6. Input Voltage vs. Output Current

#### **TYPICAL CHARACTERISTICS - NSBA114EF3**



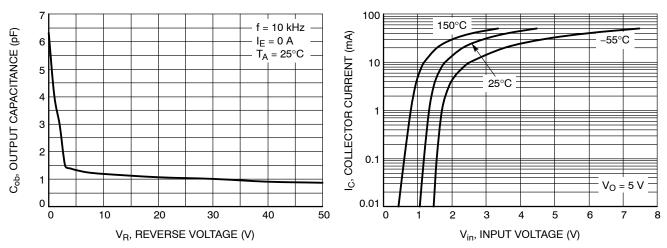


Figure 9. Output Capacitance

Figure 10. Output Current vs. Input Voltage

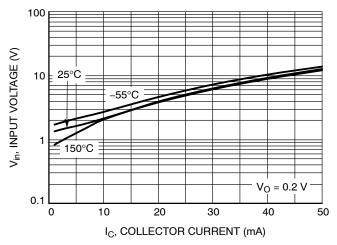
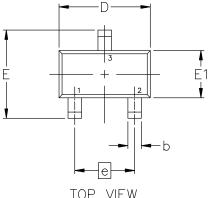
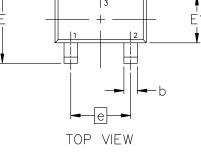


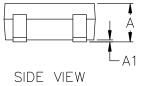
Figure 11. Input Voltage vs. Output Current

#### **PACKAGE DIMENSIONS**

#### SC-59-3 2.90x1.50x1.15, 1.90P **CASE 318D ISSUE J**



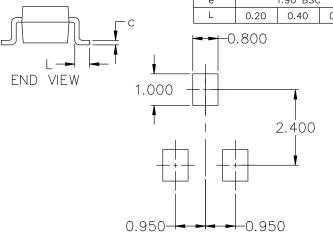




#### NOTES:

- DIMENSIONING AND TOLERANCING CONFORM TO ASME Y14.5-2018.
- 2. ALL DIMENSION ARE IN MILLIMETERS.

	MILLIMETERS			
DIM	MIN.	NOM.	MAX.	
Α	1.00	1.15	1.30	
A1	0.01	0.06	0.10	
Ь	0.35	0.43	0.50	
С	0.09	0.14	0.18	
D	2.70	2.90	3.10	
Е	2.50	2.80	3.00	
E1	1.30	1.50	1.70	
е	1.90 BSC			
L	0.20	0.40	0.60	



#### RECOMMENDED MOUNTING FOOTPRINT\*

FOR ADDITIONAL INFORMATION ON OUR Pb-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.



**MILLIMETERS** 

MIN

0.89

0.01

0.37

0.08

2.80

1.20

1.78

0.30

0.35

2.10

O°

NOM

1.00

0.06

0.44

0.14

2.90

1.30

1.90

0.43

0.54

2.40

\_\_\_

## PACKAGE DIMENSIONS



#### SOT-23 (TO-236) 2.90x1.30x1.00 1.90P **CASE 318 ISSUE AU**

**DATE 14 AUG 2024** 

MAX

1.11

0.10

0.50

0.20

3.04

1.40

2.04

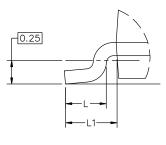
0.55

0.69

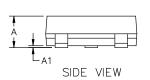
2.64

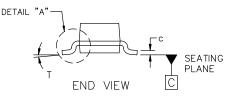
10°

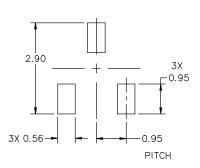




DETAIL "A" Scale 3:1









DIM

Α

Α1

b

С

D

Ε

е L

L1

HE

Τ

- DIMENSIONING AND TOLERANCING 1.
- PER ASME Y14.5M, 2018. CONTROLLING DIMENSIONS: MILLIMETERS.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE
- BASE MATERIAL.
  DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

## **GENERIC MARKING DIAGRAM\***



XXX = Specific Device Code

= Date Code

= Pb-Free Package

#### RECOMMENDED MOUNTING FOOTPRINT

\* For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### **STYLES ON PAGE 2**

DOCUMENT NUMBER:	98ASB42226B	Electronic versions are uncontrolled except when accessed directly from the Document Repos Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.			
DESCRIPTION:	SOT-23 (TO-236) 2.90x1.3	SOT-23 (TO-236) 2.90x1.30x1.00 1.90P			

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<sup>\*</sup>This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "=", may or may not be present. Some products may not follow the Generic Marking.

#### SOT-23 (TO-236) 2.90x1.30x1.00 1.90P CASE 318 ISSUE AU

DATE 14 AUG 2024

STYLE 1 THRU 5: CANCELLED	STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 7:         STYLE 8:           PIN 1. EMITTER         PIN 1. ANOD           2. BASE         2. NO CC           3. COLLECTOR         3. CATHO	ONNECTION	
STYLE 9: PIN 1. ANODE 2. ANODE 3. CATHODE	STYLE 10: PIN 1. DRAIN 2. SOURCE 3. GATE	STYLE 11:         STYLE 12:           PIN 1.         ANODE         PIN 1.         CATHO           2.         CATHODE         2.         CATHO           3.         CATHODE-ANODE         3.         ANODO	ODE 2. DRAIN 2. GATE	
STYLE 15: PIN 1. GATE 2. CATHODE 3. ANODE	STYLE 16: PIN 1. ANODE 2. CATHODE 3. CATHODE	STYLE 17:         STYLE 18:           PIN 1. NO CONNECTION         PIN 1. NO CO           2. ANODE         2. CATHO           3. CATHODE         3. ANODO	ODE 2. ANODE 2. ANODE	
STYLE 21: PIN 1. GATE 2. SOURCE 3. DRAIN	STYLE 22: PIN 1. RETURN 2. OUTPUT 3. INPUT	STYLE 23:         STYLE 24:           PIN 1. ANODE         PIN 1. GATE           2. ANODE         2. DRAIN           3. CATHODE         3. SOURCE		CTION
STYLE 27: PIN 1. CATHODE 2. CATHODE 3. CATHODE	STYLE 28: PIN 1. ANODE 2. ANODE 3. ANODE			

DOCUMENT NUMBER:	98ASB42226B Electronic versions are uncontrolled except when accessed directly from the Document Repos Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.			
DESCRIPTION:	SOT-23 (TO-236) 2.90x1.3	SOT-23 (TO-236) 2.90x1.30x1.00 1.90P		

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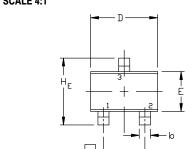


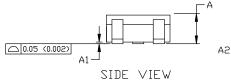
PACKAGE DIMENSIONS

#### SC-70 (SOT-323) **CASE 419** ISSUE R

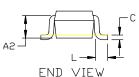
**DATE 11 OCT 2022** 







TOP VIEW



#### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH

	MILLIMETERS			INCHES		
DIM	MIN.	N□M.	MAX.	MIN.	N□M.	MAX.
Α	0.80	0.90	1.00	0.032	0.035	0.040
A1	0.00	0.05	0.10	0.000	0.002	0.004
A2		0.70 REF			0.028 BS	C
b	0.30	0.35	0.40	0.012	0.014	0.016
С	0.10	0.18	0.25	0.004	0.007	0.010
D	1.80	2.00	2.20	0.071	0.080	0.087
E	1.15	1.24	1.35	0.045	0.049	0.053
е	1.20	1.30	1.40	0.047	0.051	0.055
e1	0.65 BSC			0.026 BS	C	
L	0.20	0.38	0.56	0.008	0.015	0.022
HE	2.00	2.10	2.40	0.079	0.083	0.095



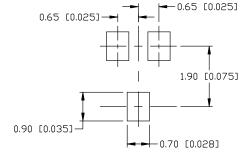


XX = Specific Device Code

Μ = Date Code

= Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.



For additional information on our Pb-Free strategy and soldering details, please download the ID Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

SOLDERING FOOTPRINT

STYLE 1: CANCELLED	STYLE 2: PIN 1. ANODE 2. N.C. 3. CATHODE	STYLE 3: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 4: PIN 1. CATHODE 2. CATHODE 3. ANODE	STYLE 5: PIN 1. ANODE 2. ANODE 3. CATHODE	
STYLE 6:	STYLE 7:	STYLE 8:	STYLE 9:	STYLE 10:	STYLE 11:
PIN 1. EMITTER	PIN 1. BASE	PIN 1. GATE	PIN 1. ANODE	PIN 1. CATHODE	PIN 1. CATHODE
2. BASE	2. EMITTER	2. SOURCE	2. CATHODE	2. ANODE	<ol><li>CATHODE</li></ol>
<ol><li>COLLECTOR</li></ol>	<ol><li>COLLECTOR</li></ol>	3. DRAIN	<ol><li>CATHODE-ANODE</li></ol>	3. ANODE-CATHODE	<ol><li>CATHODE</li></ol>

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DESCRIPTION:	SC-70 (SOT-323)		PAGE 1 OF 1

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PACKAGE DIMENSIONS

#### SC75-3 1.60x0.80x0.80, 1.00P

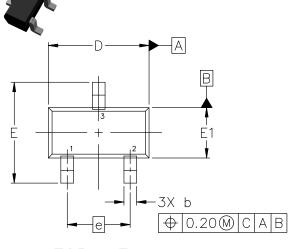
**CASE 463 ISSUE H** 

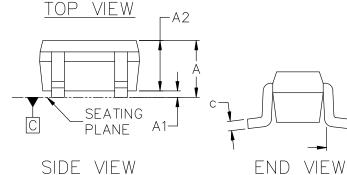
**DATE 01 FEB 2024** 

#### NOTES:

- DIMENSIONING AND TOLERANCING CONFORM TO ASME Y14.5-2018.
- ALL DIMENSION ARE IN MILLIMETERS.

DIM	MILLIMETERS			
DIIVI	MIN.	NOM.	MAX.	
А	0.70	0.80	0.90	
A1	0.00	0.05	0.10	
A2	(	0.80 REF		
Ь	0.15	0.20	0.30	
С	0.10	0.15	0.25	
D	1.55	1.60	1.65	
E	1.50	1.60	1.70	
E1	0.70	0.80	0.90	
е	1.00 BSC			
L	0.10	0.15	0.20	







#### **GENERIC MARKING DIAGRAM\***



XX = Specific Device Code

Μ = Date Code

= Pb-Free Package

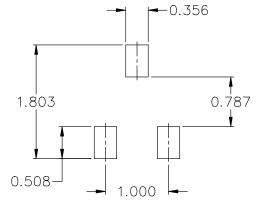
\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

STYLE 1: PIN 1. BASE 2. EMITTER 3 COLLECTOR

STYLE 4:

STYLE 2: PIN 1. ANODE 2. N/C 3. CATHODE STYLE 3: PIN 1. ANODE 2. ANODE

3 CATHODE



#### RECOMMENDED MOUNTING FOOTPRINT\*

FOR ADDITIONAL INFORMATION ON OUR Pb-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

PIN 1. CATHODE	PIN
2. CATHODE	
<ol><li>ANODE</li></ol>	

**DOCUMENT NUMBER:** 

STYLE 5: PIN 1. GATE 2. SOURCE 3. DRAIN

98ASB15184C

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**DESCRIPTION:** 

SC75-3 1.60x0.80x0.80, 1.00P

PAGE 1 OF 1

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## PACKAGE DIMENSIONS

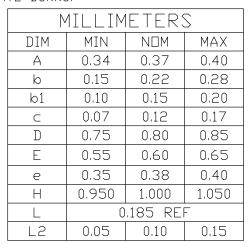


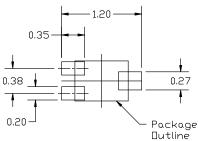
#### SOT-1123 0.80x0.60x0.37, 0.35P CASE 524AA ISSUE D

**DATE 18 JAN 2024** 

#### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
- CONTROLLING DIMENSION: MILLIMETERS. 2.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.



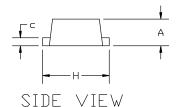


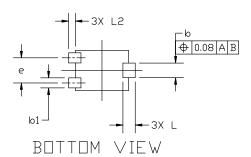
#### RECOMMENDED MOUNTING FOOTPRINT

\*For additional information on our Pb-Free strategy and soldering details, please download the IN Semiconductor Soldering and Mounting Techniques Reference manual, SOLDERRM/D.

# В

ТПР VIEW





#### **GENERIC MARKING DIAGRAM\***



= Specific Device Code

= Date Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

STYLE 1:	STYLE 2:
PIN 1. BASE	PIN 1. ANODE
<ol><li>EMITTER</li></ol>	2. N/C
<ol><li>COLLECTOR</li></ol>	<ol><li>CATHOD</li></ol>

STYLE 3: PIN 1. ANODE 2. ANODE 3. CATHODE

STYLE 4: PIN 1. CATHODE 2. CATHODE 3. ANODE

STYLE 5: PIN 1. GATE 2. SOURCE

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DESCRIPTION:	SOT-1123 0.80x0.60x0.37,	0.35P	PAGE 1 OF 1

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PACKAGE DIMENSIONS

MILLIMETERS

 $N\square M$ .

0.50

0.21

0.31

0.12

1.20

0.80

0.40 BSC

1.20

0.29 REF



#### SOT-723 1.20x0.80x0.50, 0.40P CASE 631AA ISSUE E

**DATE 24 JAN 2024** 

MAX.

0.55

0.27

0.37

0.17

1.25

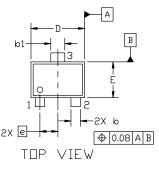
0.85

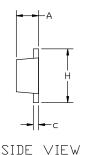
1.25

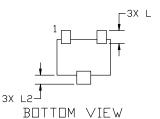
0.25

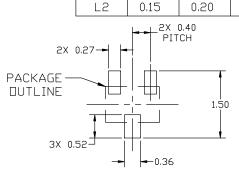
#### NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
- CONTROLLING DIMENSION: MILLIMETERS.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.









DIM

Α

b

b1

 $\subset$ D

Ε

е Н

L

MIN.

0.45

0.15

0.25

0.07

1.15

0.75

1.15

#### RECOMMENDED MOUNTING FOOTPRINT

\*For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

#### **GENERIC MARKING DIAGRAM\***



XX = Specific Device Code = Date Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

STYLE 1: STYLE 2: STYLE 3: STYLE 4: STYLE 5: PIN 1. GATE 2. SOURCE PIN 1. BASE PIN 1. ANODE PIN 1. ANODE PIN 1. CATHODE 2 FMITTER 2 CATHODE 2 N/C 2. ANODE 3. COLLECTOR 3. CATHODE 3. CATHODE 3. DRAIN

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DESCRIPTION:	SOT-723 1.20x0.80x0.50, 0.40P		PAGE 1 OF 1

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